Reflectionless
High Pass Filter

XHF2-Series

50Ω DC to 30 GHz

CASE STYLE: MC1630-1

The Big Deal

- *Patented design eliminates in band spurs*
- *Pass band cut-off up to 18.3 GHz*
- *Stop band up to 30 GHz*
- *Excellent repeatability through IPD* process*

Product Overview

Mini-Circuits' XHF2-Series reflectionless filters employs a novel filter topology which absorbs and terminates stop band signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stop band, sending signals back to the source at 100% of the power level which interact with neighboring components and often result in intermodulation and other interferences. Reflectionless filters eliminate stop band reflections, allowing them to be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

Key Features	*Advantages*
Easy integration with sensitive reflective components, e.g. mixers, multipliers	Reflectionless filters absorb unwanted signals, preventing reflections back to the source. This reduces generation of additional unwanted signals without the need for extra components like attenuators, improving system dynamic range and saving board space.
Enables stable integration of wideband amplifiers	Because reflectionless filters maintain good impedance in the stop band; they can be integrated with high gain, wideband amplifiers without the risk of creating instabilities in these out of band regions.
Cascadable	Reflectionless filters can be cascaded in multiple sections to provide sharper and higher attenuation, while also preventing any standing waves that could affect pass band signals.
Excellent power handling in a tiny surface mount device	High power handling extends the usability of these filters to the transmit path for inter-stage filtering.
Small size, 2x2mm QFN	Allows replacement of filter/attenuator pairs with a single reflectionless filter, saving board space.
Excellent repeatability of RF performance	Through semiconductor IPD process, X-series filters are inherently repeatable for large volume production.
Excellent stability over temperature	With ±0.3 dB variation over temperature ideal for use in wide temperature range applications without the need for additional temperature compensation.
Operating temperature up to 105˚C	Suitable for operation close to high power components.

*IPD – Integrated Passive Device, is a GaAs semiconductor process

Reflectionless
High Pass Filter

XHF2-153+

50Ω 15.3 to 30 GHz

Features

- Match to 50Ω in the stop band, eliminates undesired reflections
- Cascadable
- Excellent Power handling
- Temperature stable, up to 105°C
- Small size, 2 x 2 mm
- Protected by US Patent No. 8,392,495

Generic photo used for illustration purposes only

CASE STYLE: MC1630-1

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

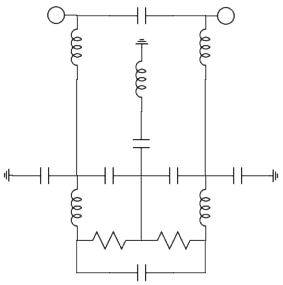
Applications

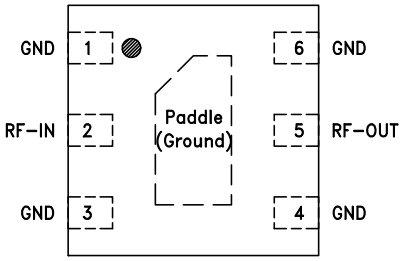
- Wi-Fi
- WiMax
- Microwave Radio
- Military & Space

General Description

Mini-Circuits' XHF2-153+ reflectionless filter employs a novel filter topology which absorbs and terminates stop band signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stop band, sending signals back to the source at 100% of the power level. These reflections interact with neighboring components and often result in inter-modulation and other interferences. Reflectionless filters eliminate stop band reflections, allowing them to be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

simplified schematic and pad description





Function	Pad Number	Description
RF-IN	2	RF Input Pad
RF-OUT	5	RF Output Pad
GND	1,3,4,6, Paddle	Connected to ground externally

Electrical Specifications[1] at 25°C

Parameter		F#	Frequency (MHz)	Min.	Typ.	Max.	Unit
Stop Band	Rejection	DC - F'	DC - 2400	—	6.8	—	dB
		F' - F1	2400 - 12000	12.0	13.7	—	
	Frequency Cut-off	F2	14200	—	2.9	—	
	VSWR	DC - F'	DC - 2400	—	2.7	—	:1
		F' - F1	2400 - 12000	—	2.2	—	
Pass Band	Insertion Loss	F3 - F4	15300 - 26000	—	1.8	—	dB
		F4 - F5	26000 - 30000	—	0.7	—	
	VSWR	F3 - F4	15300 - 26000	—	2.1	—	:1
		F4 - F5	26000 - 30000	—	1.6	—	

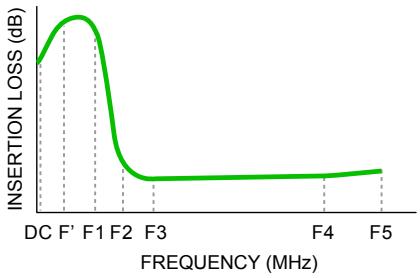
[1] Measured on Mini-Circuits Characterization Test Board TB-883-153+

Absolute Maximum Ratings[4]

Parameter	Ratings
Operating Temperature	-55°C to +105°C
Storage Temperature	-65°C to +150°C
RF Power Input, Passband (F3-F5)[2]	1.26W at 25°C
RF Power Input, Stopband (DC-F3)[3]	0.16W at 25°C

[2] Passband rating derates linearly to 0.63W at 105°C ambient
[3] Stopband rating derates linearly to 0.08W at 105°C ambient
[4] Permanent damage may occur if any of these limits are exceeded.

Specification Definition



ESD rating

Human body model (HBM): Class 1A (250 to<500 V) in accordance with ANSI/ESD 5.1-2001

Typical Performance Data at 25°C

Frequency (MHz)	Insertion Loss (dB)	VSWR (:1)
100	6.83	2.59
500	7.31	2.61
1000	8.72	2.60
1500	10.78	2.51
2000	13.33	2.34
2400	15.63	2.15
3000	19.15	1.85
4000	20.71	1.44
8000	27.73	1.41
10000	17.45	1.45
12000	14.37	1.77
14500	2.72	1.38
16000	1.47	1.32
18000	0.99	1.22
20000	1.29	1.92
26000	0.81	1.24
30000	0.96	1.27